

**Green Products** 

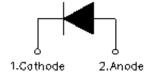
## **MBR1545 SCHOTTKY RECTIFIER**

#### **Applications:**

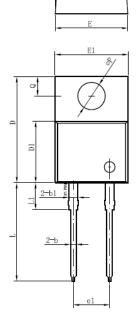
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

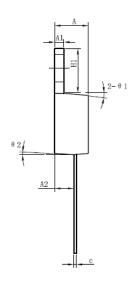
#### Features:

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- . Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



# **Mechanical Dimensions (In mm)**





Symbol	Dimensions in			
Syllibol				
	millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.55	8.07	8.85	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1		5.08		
H1	6.04	6.24	6.44	
Ш	13.00	13.86	14.08	
L1		3.80		
ФР	3.74	3.84	4.04	
Ø	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

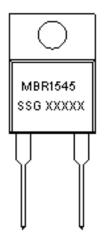
#### **TO-220AC**

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



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# **Marking Diagram:**



Where XXXXX is YYWWL

MBR = Device Type

15 = Forward Current (15A) 45 = Reverse Voltage (45V)

SSG = SSG YY = Year WW = Week

L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Ordering Information:**

Device	Package	Shipping	
MBR1545	TO-220AC(Pb-Free)	50pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}$	-	45	
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =123 °C, rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	240	А

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 15 A, Pulse, T <sub>J</sub> = 25 °C	0.70	V
	$V_{F2}$	@ 15 A, Pulse, T <sub>J</sub> = 125 °C	0.60	V
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = rated V_R$	1.0	mA
		$T_C = 25  ^{\circ}C$		
	$I_{R2}$	$@V_R = rated V_R$	40	mA
		T <sub>C</sub> = 125 °C		
Junction Capacitance	$C_T$	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	800	pF
(per leg)		$f_{SIG} = 1MHz$		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nΗ
(per leg)		package body		
Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	1.6	°C/W
Approximate Weight	wt	-	1.6	g
Case Style		TO-220AC		

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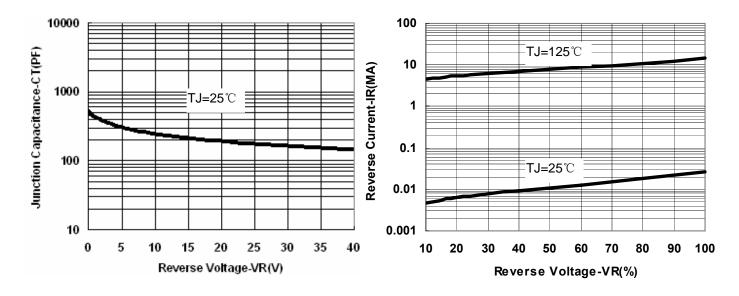


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

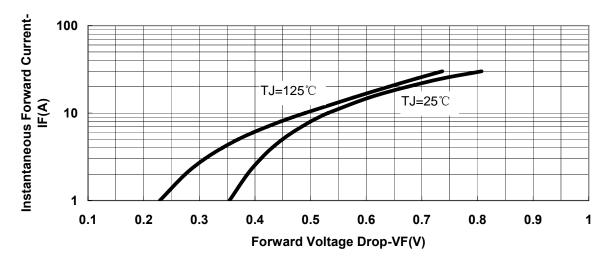


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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